



SANYO Semiconductors

DATA SHEET

2SA2179

 — PNP Epitaxial Planar Silicon Transistor
50V / 13A High-Speed Switching Applications

Applications

- High-speed switching applications (switching regulators, drive circuit).

Features

- Adoption of MBIT processes.
- Large current capacitance.
- Low collector-to-emitter saturation voltage.
- High-speed switching.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		-50	V
Collector-to-Emitter Voltage	V _{CEO}		-50	V
Emitter-to-Base Voltage	V _{EB0}		-6	V
Collector Current	I _C		-13	A
Collector Current (Pulse)	I _{CP}		-15	A
Base Current	I _B		-2	A
Collector Dissipation	P _C		2	W
		T _C =25°C	25	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I _{CBO}	V _{CB} =-40V, I _E =0A			-10	μA
Emitter Cutoff Current	I _{EB0}	V _{EB} =-4V, I _C =0A			-10	μA
DC Current Gain	h _{FE1}	V _{CE} =-2V, I _C =-270mA	200		500	
	h _{FE2}	V _{CE} =-2V, I _C =-8.1A	50			
Gain-Bandwidth Product	f _T	V _{CE} =-5V, I _C =-700mA		110		MHz
Output Capacitance	C _{ob}	V _{CB} =-10V, f=1MHz		100		pF

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SANYO Electric Co.,Ltd. Semiconductor Company

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

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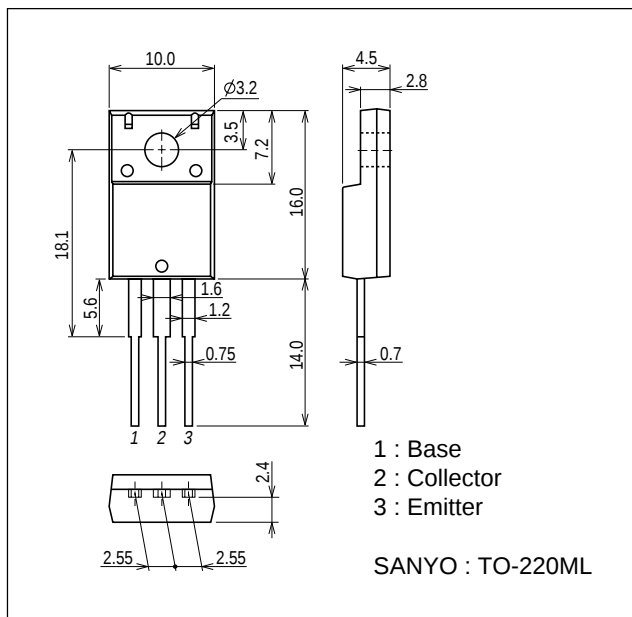
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -6A, I_B = -300mA$		-250	-500	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -6A, I_B = -300mA$			-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -100\mu A, I_E = 0A$	-50			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -100\mu A, I_C = 0A$	-6			V
Turn-ON Time	t_{on}	See specified Test Circuit.		80		ns
Storage Time	t_{stg}	See specified Test Circuit.		265		ns
Fall Time	t_f	See specified Test Circuit.		43		ns

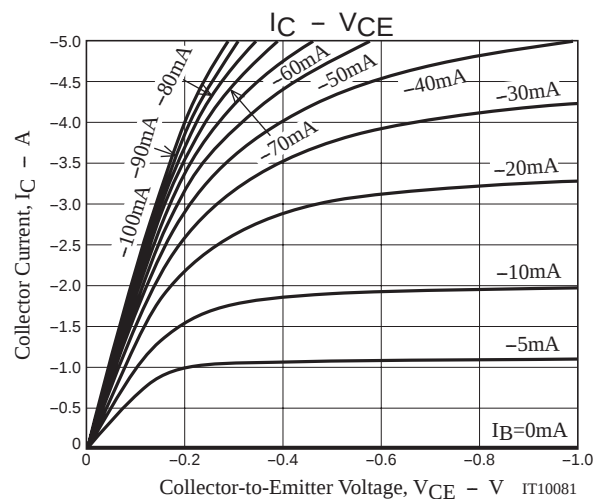
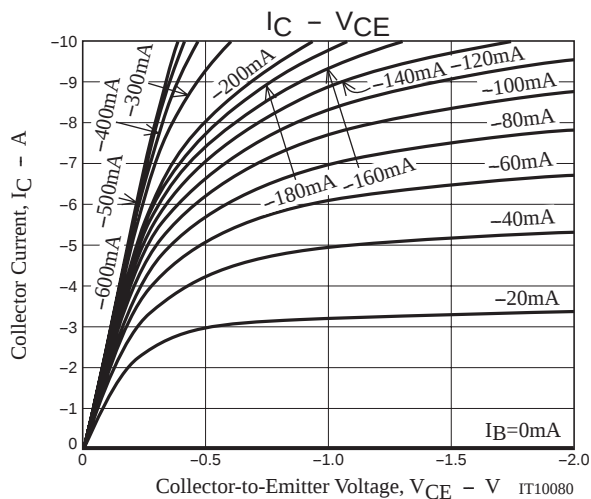
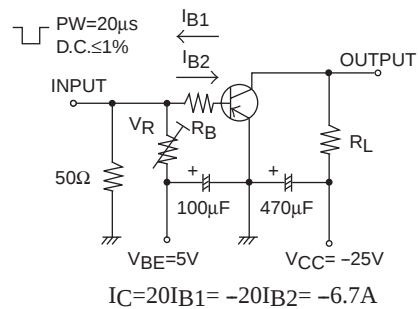
Package Dimensions

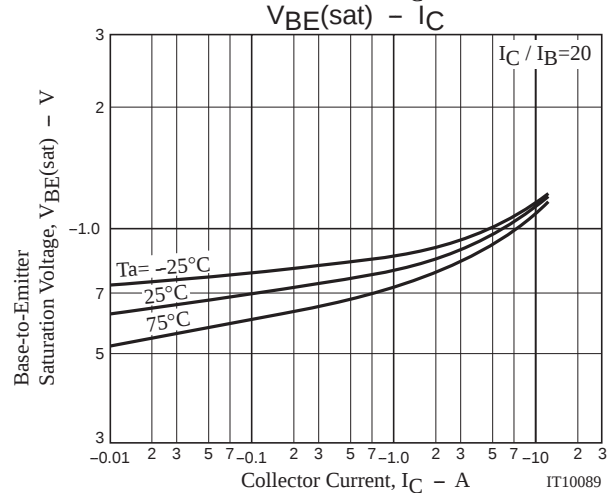
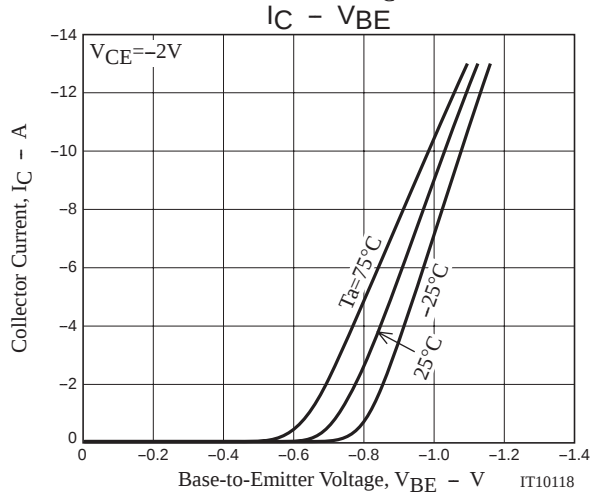
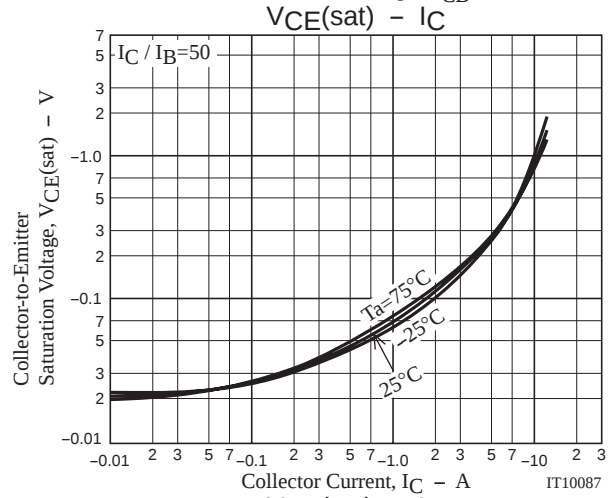
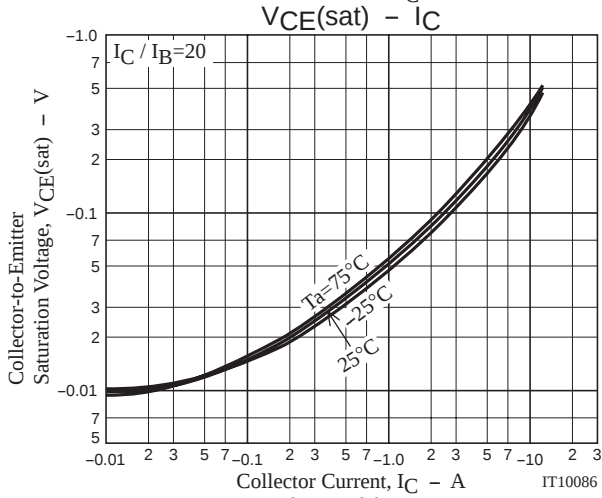
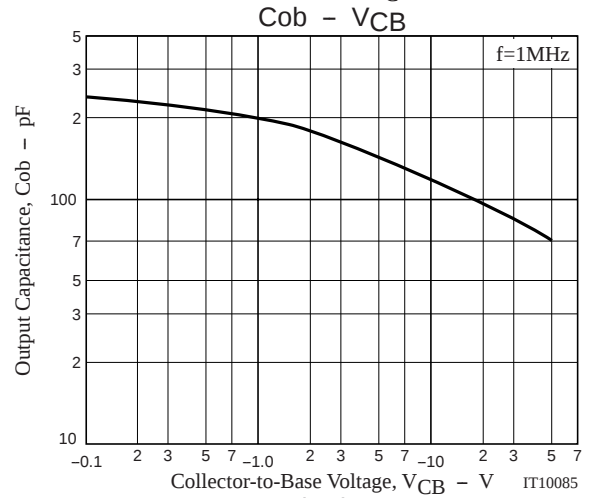
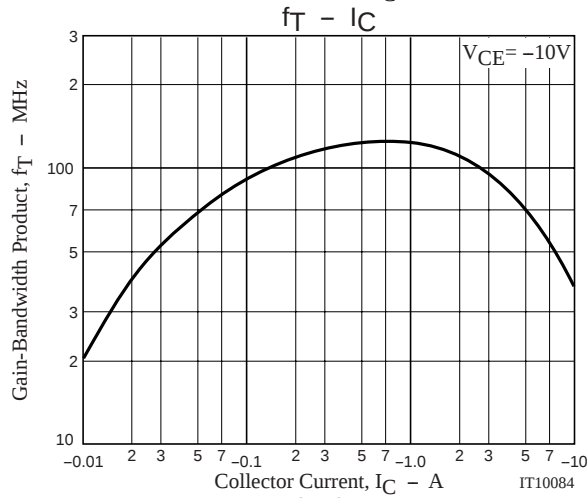
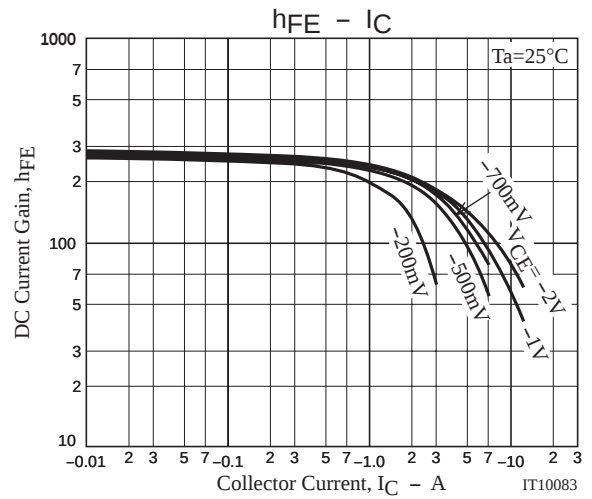
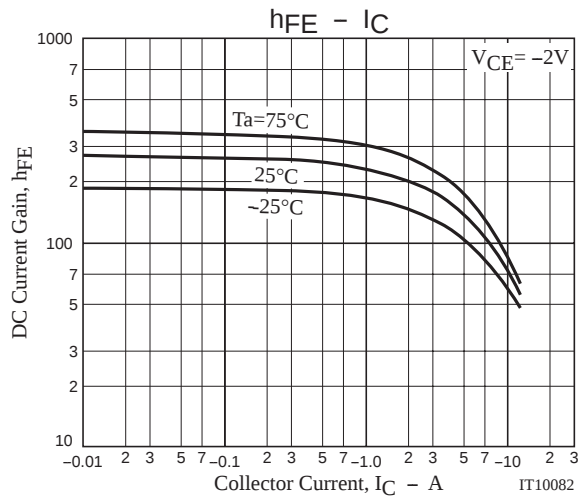
unit : mm

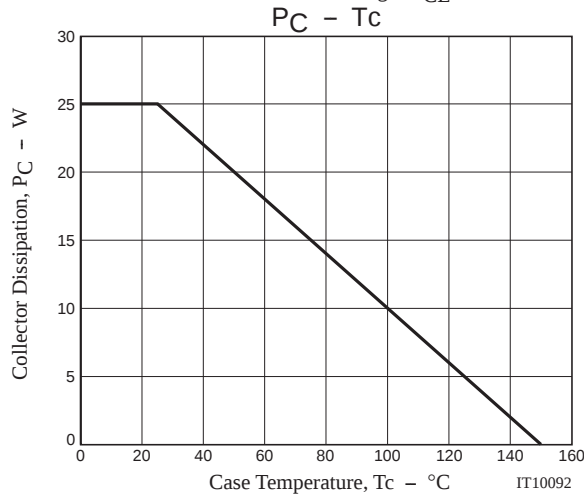
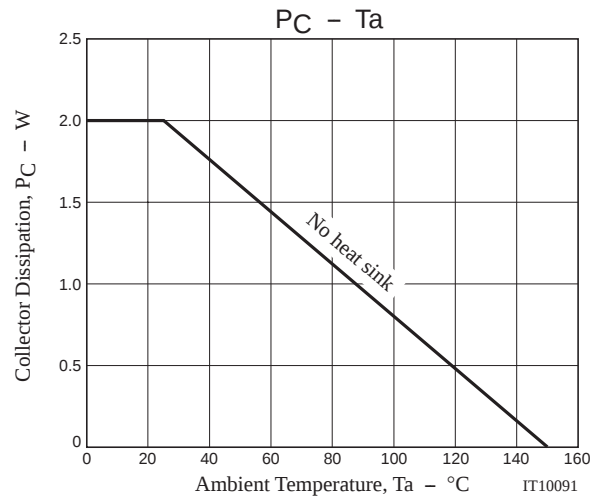
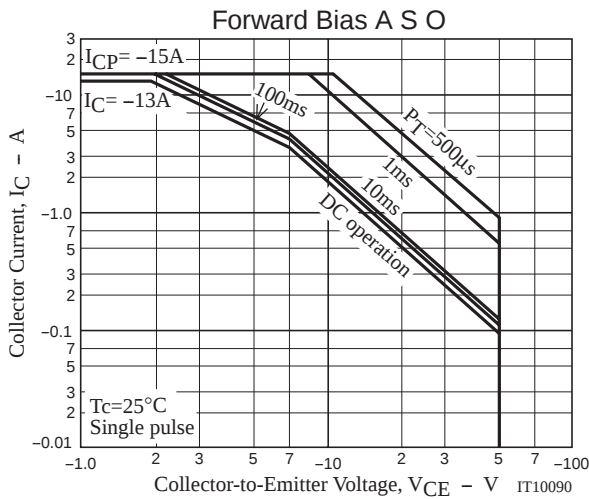
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Switching Time Test Circuit







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